## **DIODE MODULE**

# **DD130F**







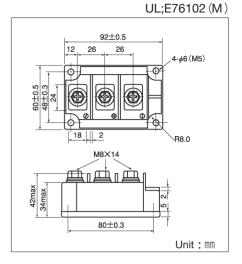
Power Diode Module **DD130F** series are designed for various rectifier circuits. **DD130F** has two diode chips connected in series in a package and the mounting base is electrically isolated from elements for simple heatsink construction. Wide voltage rating up to, 1,600V is avaiable for various input voltage.

- Isolated mounting base
- Two elements in a package for simple (single and three phase) bridge connections
- Highly reliable glass passivated chips
- High surge current capability

### (Applications)

Various rectifiers, Battery chargers, DC motor drives





■Maximum Ratings (Tj=25°C)

Symbol	Itam	Ratings				Linit
	Item	DD130F40	DD130F80	DD130F120	DD130F160	Unit
VRRM	Repetitive Peak Reverse Voltage	400	800	1200	1600	V
VRSM	Non-Repetitive Peak Reverse Voltage	480	960	1300	1700	V

Symbol	l	tem	Conditions	Ratings	Unit
lf (AV)	Average Forward Current Single phase, half wave, 180° conduction, Tc: 90°C			130	Α
IF (RMS)	R.M.S. Forward Current		Single phase, half wave, 180° conduction, Tc:90°C	205	Α
Iгям	Surge Forward Current		½ cycle, 50/60Hz, peak value, non-repetitive	4000/4400	Α
l²t	l²t		Value for one cycle of surge current	80000	A <sup>2</sup> S
Viso	Isolation Breakdown Voltage (R.M.S)		A.C.1minute	2500	°C
Tj	Junction Temperature			<b>−</b> 40∼ <b>+</b> 125	°C
Tstg	Storage Temperature			<b>−</b> 40∼ <b>+</b> 125	V
	Mounting	Mounting (M5)	Recommended Value 1.5~2.5 (15~25)	2.7 (28)	N⋅m
	Torque	Terminal (M8)	Recommended Value 8.8~10 (90~105)	11 (115)	(kgf·cm)
	Mass			510	g

#### ■Flectrical Characteristics

Liectrical Orial acteristics							
Symbol	Item Conditions		Ratings	Unit			
IRRM	Repetitive Peak Reverse Current, max.	at VDRM, single phase, half wave. Tj=125℃	50	mA			
VFM	Forward Voltage Drop, max.	Forward current 400A, Tj=25°C, Inst. measurement	1.40	V			
Rth (i-c)	Thermal Impedance, max.	Junction to case	0.20	°C/W			

## **DD130F**







